

5150-pixel CCD Linear Sensor (B/W)

Description

The ILX510 is a reduction type CCD linear sensor developed for high resolution copiers. This sensor reads A3-size documents at a density of 400 DPI, and A4-size documents at a density of 600 DPI at high speed.

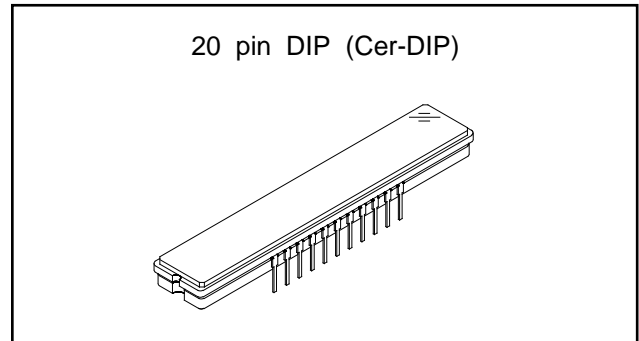
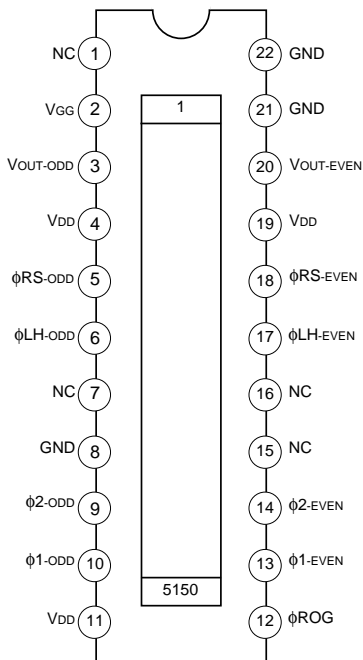
Features

- Number of effective pixels: 5150 pixels
- Pixel size: 7 μm×7 μm (7 μm pitch)
- Signal output phase of two-output simultaneous-output (alternate-output is available)
- Ultra high sensitivity/Ultra low lag
- Max Data Rate: 40 MHz
- Single 12 V power supply
- Input Clock Pulse: CMOS 5V drive
- Package: 22 pin cer-DIP (400 mil)

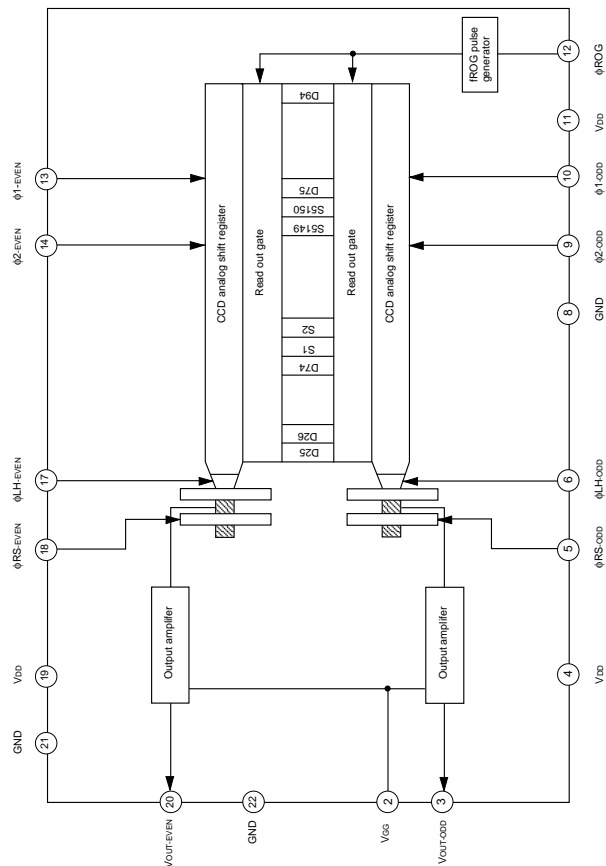
Absolute Maximum Ratings

- Supply voltage VDD 15 V
- Operating temperature -10 to +60 °C
- Storage temperature -30 to +80 °C

Pin Configuration (TOP VIEW)



Block Diagram



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**Pin Description**

Pin No	Symbol	Description	Pin No	Symbol	Description
1	NC	NC	12	$\phi$ ROG	Readout gate clock pulse input
2	V <sub>GG</sub>	Output circuit gate bias	13	$\phi$ 1-EVEN	Clock pulse input (even pixel)
3	V <sub>OUT-ODD</sub>	Signal out (odd pixel)	14	$\phi$ 2-EVEN	Clock pulse input (even pixel)
4	V <sub>DD</sub>	12 V power supply	15	NC	NC
5	$\phi$ RS-ODD	Clock pulse input (odd pixel)	16	NC	NC
6	$\phi$ LH-ODD	Clock pulse input (odd pixel)	17	$\phi$ LH-EVEN	Clock pulse input (even pixel)
7	NC	NC	18	$\phi$ RS-EVEN	Clock pulse input (even pixel)
8	GND	GND	19	V <sub>DD</sub>	12 V power supply
9	$\phi$ 2-ODD	Clock pulse input (odd pixel)	20	V <sub>OUT-EVEN</sub>	Signal out (even pixel)
10	$\phi$ 1-ODD	Clock pulse input (odd pixel)	21	GND	GND
11	V <sub>DD</sub>	12 V power supply	22	GND	GND

**Recommended Supply Voltage**

Item	Min.	Typ.	Max.	Unit
V <sub>DD</sub>	11.4	12	12.6	V

**Clock Characteristics**

Item	Symbol	Min.	Typ.	Max.	Unit
Input capacity of $\phi$ 1*, $f$ 2*	C $\phi$ 1, C $\phi$ 2	—	400	—	pF
Input capacity of $\phi$ LH*	C $\phi$ LH	—	10	—	pF
Input capacity of $\phi$ RS*	C $\phi$ RS	—	10	—	pF
Input capacity of $\phi$ ROG	C $\phi$ ROG	—	10	—	pF

\*It indicates that  $\phi$ 1-ODD,  $\phi$ 1-EVEN as  $\phi$ 1,  $\phi$ 2-ODD,  $\phi$ 2-EVEN as  $\phi$ 2,  $\phi$ LH-ODD,  $\phi$ LH-EVEN as  $\phi$ LH,  $\phi$ RS-ODD,  $\phi$ RS-EVEN as  $\phi$ RS.

**Clock Frequency**

Item	Symbol	Min.	Typ.	Max.	Unit
$\phi$ 1, $\phi$ 2, $\phi$ LH, $\phi$ RS	$f\phi$ 1, $f\phi$ 2, $f\phi$ LH, $f\phi$ RS	—	1	20	MHz
Data rate	$f\phi$ R	—	2	40	MHz

**Input Clock Pulse Voltage Condition**

Item		Min.	Typ.	Max.	Unit
$\phi$ 1, $\phi$ 2, $\phi$ LH, $\phi$ RS, $\phi$ ROG pulse voltage	High level	4.75	5.0	5.25	V
	Low level	—	0	0.1	V

**Electrooptical Characteristics (Note 1)**(Ta = 25 °C, VDD = 12 V, Data rate f<sub>DR</sub>=2 MHz, Simultaneous output, Input clock =5 Vp-p

Light source = 3200 K, IR cut filter CM-500S (t = 1.0 mm)

Item	Symbol	Min.	Typ.	Max.	Unit	Remarks
Sensitivity 1	R1	9	12	15	V/(lx • s)	Note2
Sensitivity 2	R2	—	27.4	—	V/(lx • s)	Note3
Sensitivity nonuniformity	PRNU	—	4	10	%	Note4
Saturation output voltage	V <sub>SAT</sub>	1.0	1.5	—	V	Note5
Saturation exposure	SE	0.067	0.125	—	lx • s	Note6
Register imbalance	RI	—	2	7	%	Note7
Dark voltage average	V <sub>DRK</sub>	—	0.3	2.0	mV	Note8
Dark signal nonuniformity	DSNU	—	0.6	3.0	mV	Note9
Image lag	IL	—	0.02	—	%	Note10
Supply current	I <sub>VDD</sub>	—	30	60	mA	—
Total transfer efficiency	TTE	92	98	—	%	—
Output impedance	Z <sub>o</sub>	—	150	—	Ω	—
Offset level	V <sub>OS</sub>	—	6.5	—	V	Note11
Dynamic range	DR	500	5000	—	—	Note12

**Note**

- 1) In accordance with the given electrooptical characteristics, the even black level is defined as the average value of D6, D8 to D24. The odd black level is defined as the average value of D5, D7 to D23.
- 2) For the sensitivity test light is applied with a uniform intensity of illumination.
- 3) W lamp (2854 K).
- 4) PRNU is defined as indicated below. Ray incidence conditions are the same as for Note 2.  
V<sub>OUT</sub>=500 mV (Typ.)

$$PRNU = \frac{(V_{MAX} - V_{MIN})/2}{V_{AVE}} \times 100 (\%)$$

Where the 5150 pixels are divided into blocks of 103, even and odd pixels, respectively. The maximum output of each block is set to V<sub>MAX</sub>, the minimum output to V<sub>MIN</sub> and the average output to V<sub>AVE</sub>.

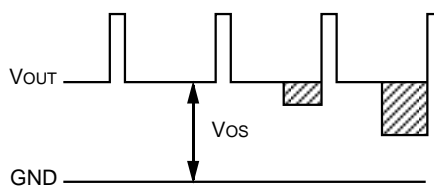
- 5) Use below the minimum value of the saturation output voltage.
- 6) Saturation exposure is defined as follows.  $SE = \frac{V_{SAT}}{R1}$
- 7) RI is defined as indicated below. V<sub>OUT</sub>=500 mV (Typ.)

$$RI = \left( \frac{|V_{ODD-AVE} - V_{EVEN-AVE}|}{\frac{V_{ODD-AVE} + V_{EVEN-AVE}}{2}} \right) \times 100 (\%)$$

Where average of odd pixels output is set to V<sub>ODD-AVE</sub>, even pixels to V<sub>EVEN-AVE</sub>.

- 8) Optical signal accumulated time  $\tau_{int}$  stands at 10 ms.
- 9) The difference between the maximum and average values of the dark output voltage is calculated for even and odd respectively. The larger value is defined as the dark signal nonuniformity. Optical signal accumulated time  $t_{int}$  stands at 10 ms.
- 10)  $V_{OUT} = 500 \text{ mV}$  (Typ.)

- 11)  $V_{os}$  is defined as indicated below.

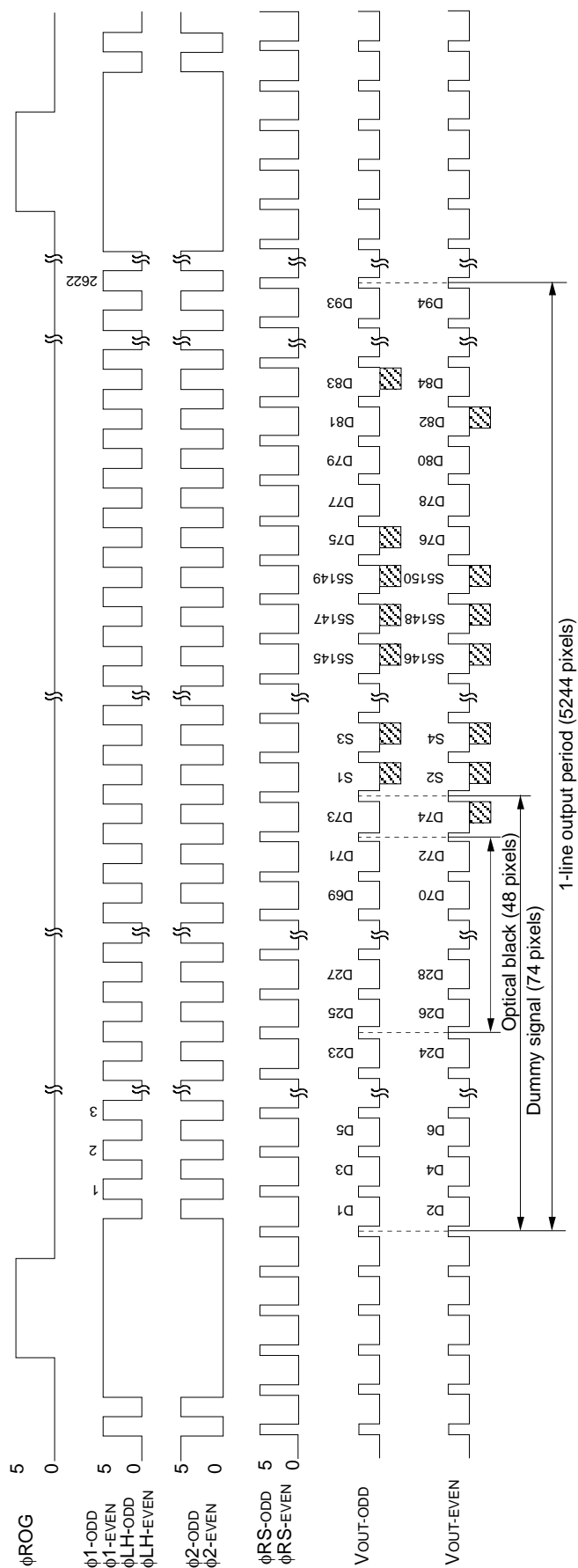


- 12) Dynamic range is defined as follows.

$$DR = \frac{V_{SAT}}{V_{DRK}}$$

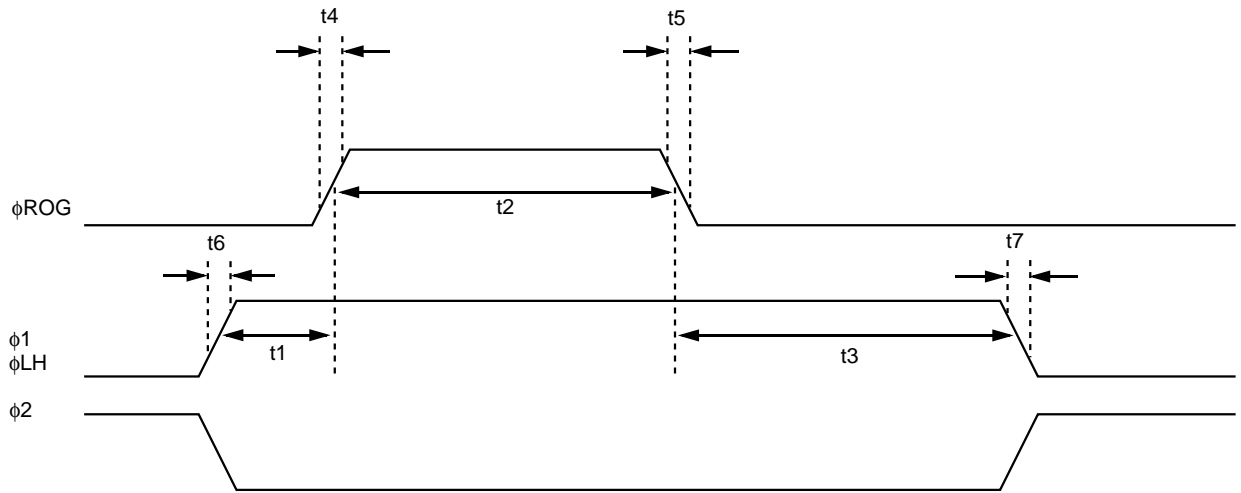
When the optical signal accumulated time is shorter, the dynamic range gets wider because the optical signal accumulated time is in proportion to the dark voltage.

**Clock Timing Chart 1 (simultaneous output)**

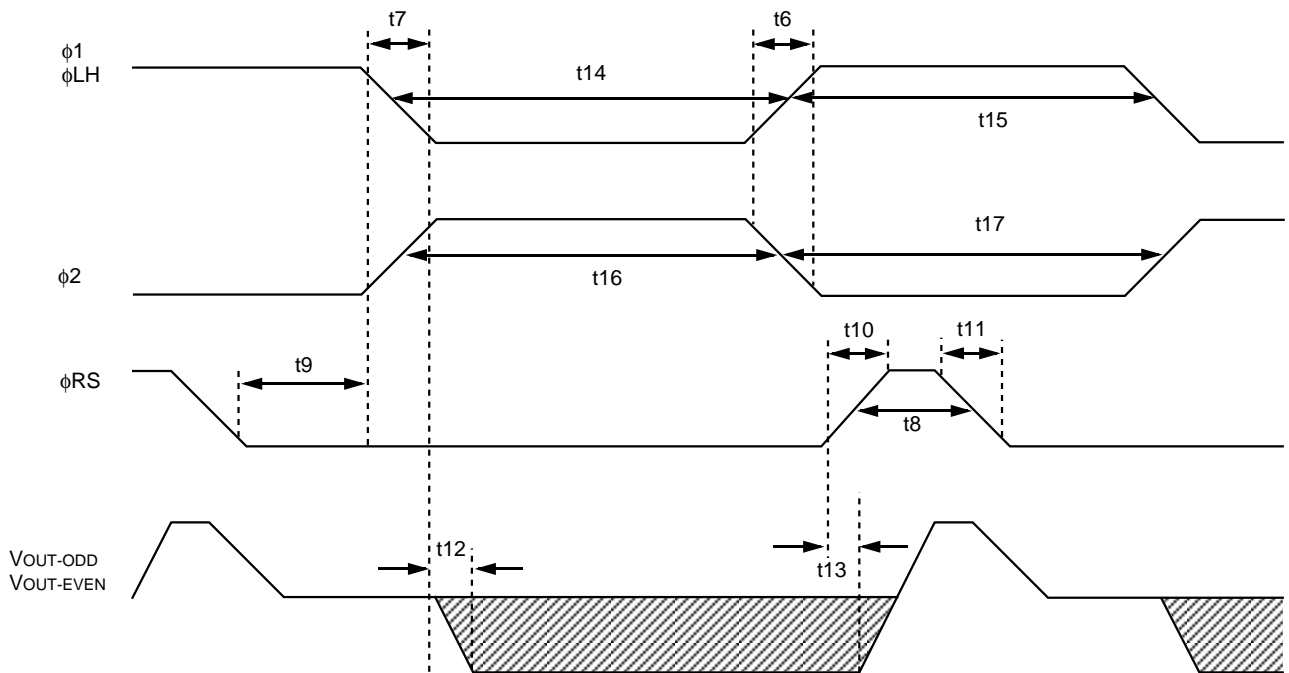


Note) The transfer pulses ( $\phi$ 1,  $\phi$ 2,  $\phi$ LH) must have more than 2622 cycles.

**Clock Timing Chart 2**



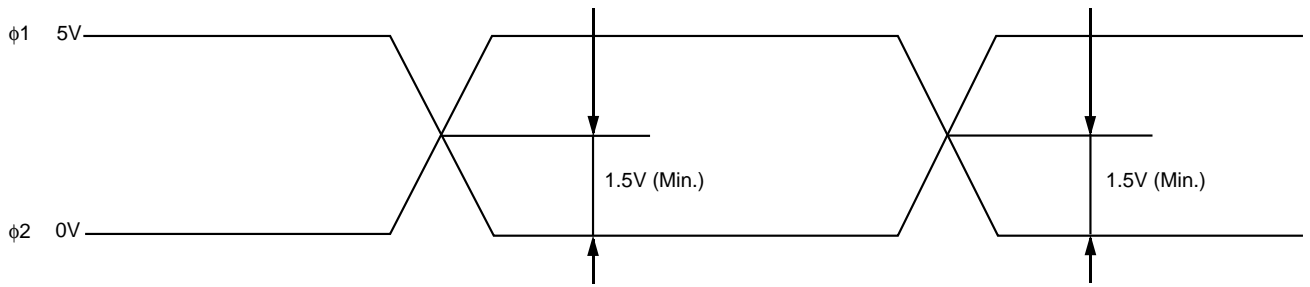
**Clock Timing Chart 3**



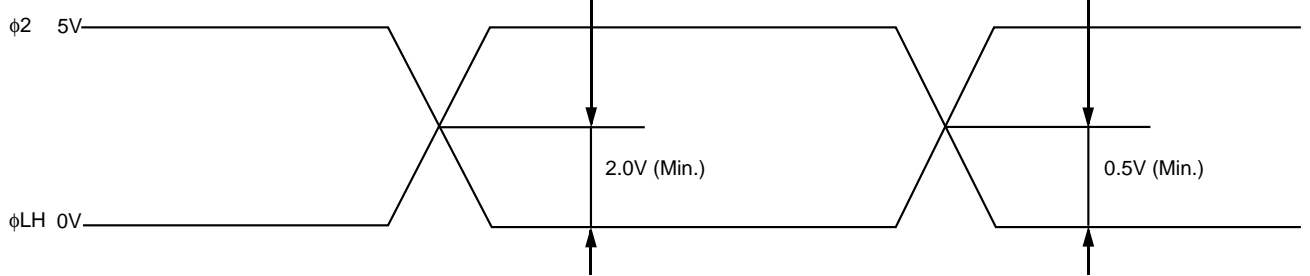
Clock timing of  $\phi_1$ ,  $\phi_2$ ,  $\phi_{LH}$ ,  $\phi_{RS}$ , and  $V_{OUT}$  at odd or even are the same as timing chart 3 in the case of alternate output.

**Clock Timing Chart 4**

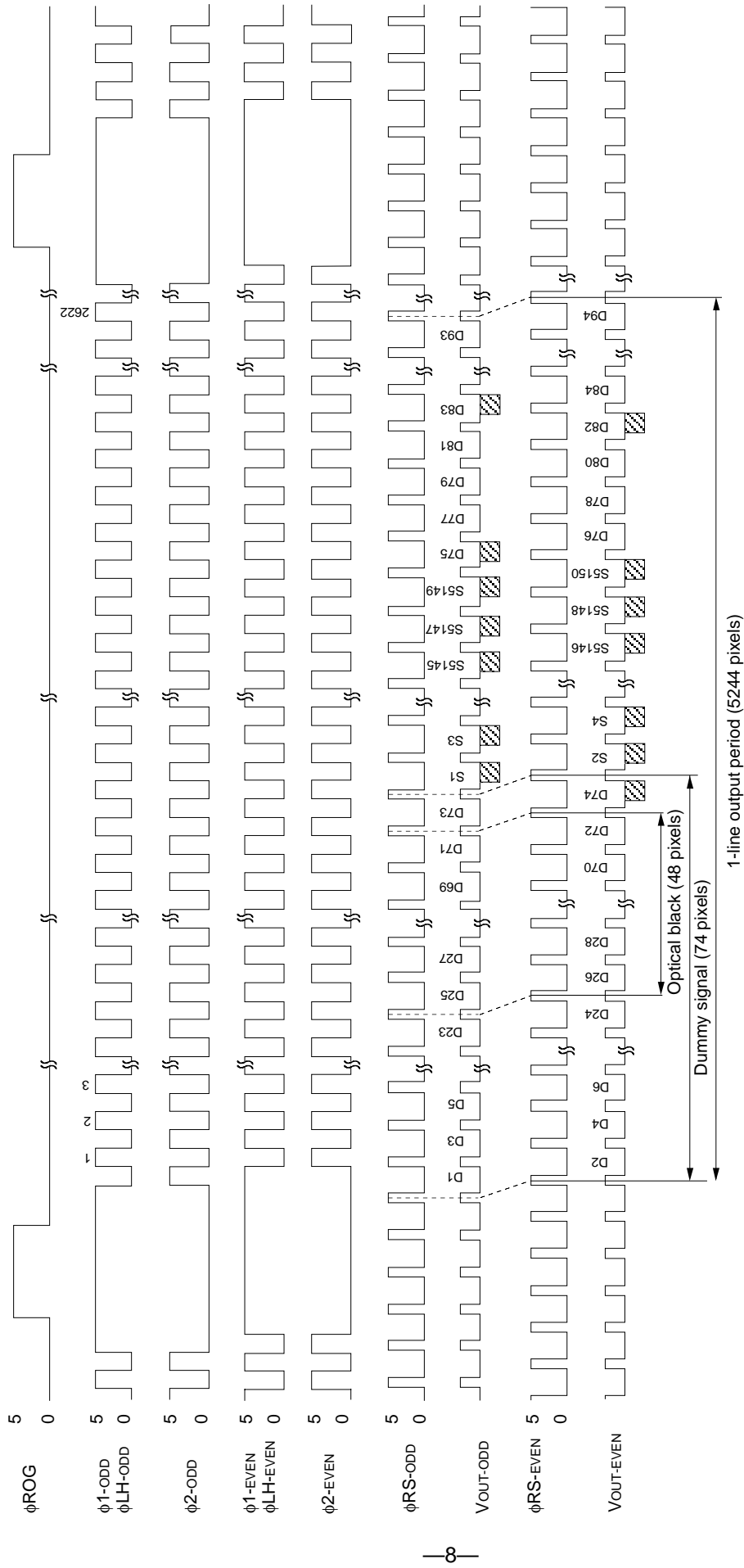
Cross point  $\phi 1$  and  $\phi 2$



Cross point  $\phi LH$  and  $\phi 2$



**Clock Timing Chart 5 (alternate output)**



Note) The transfer pulses ( $\phi$ 1,  $\phi$ 2,  $\phi$ LH) must have more than 2622 cycles.

\*Alternate output is available by making  $\phi$ 1-EVEN,  $\phi$ 2-EVEN,  $\phi$ LH-EVEN,  $\phi$ RS-EVEN delayed to  $\phi$ 1-ODD,  $\phi$ 2-ODD,  $\phi$ LH-ODD,  $\phi$ RS-ODD for half a cycle.



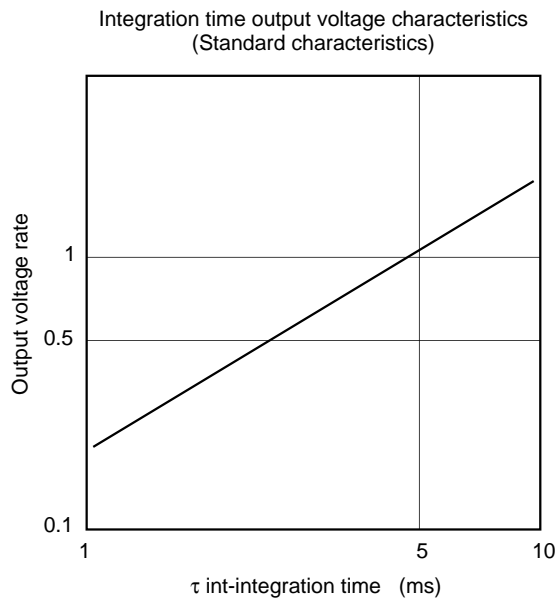
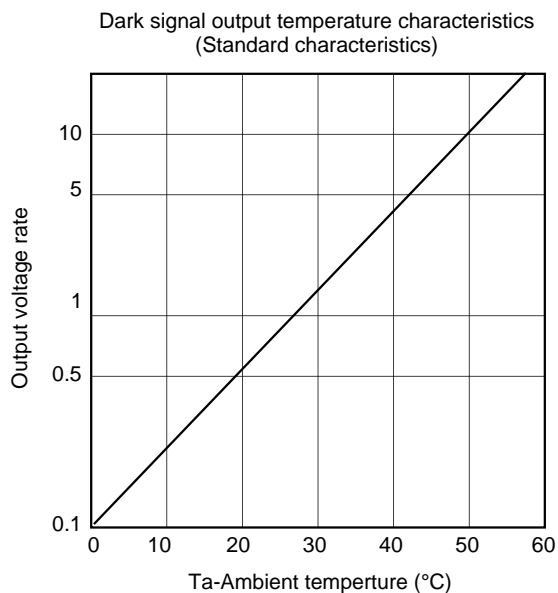
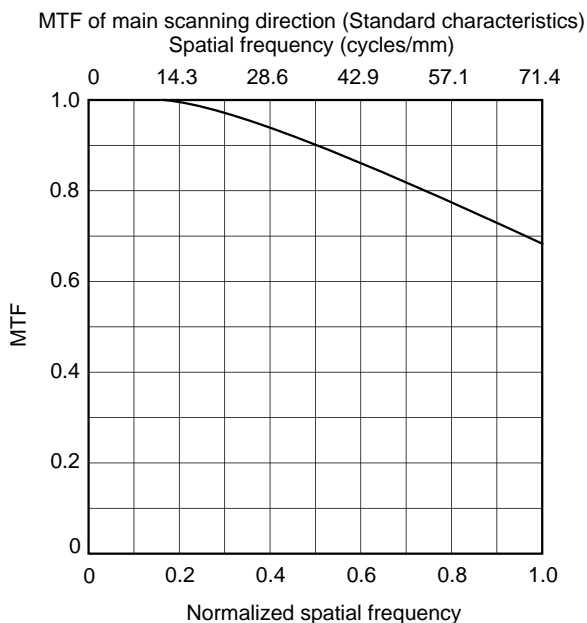
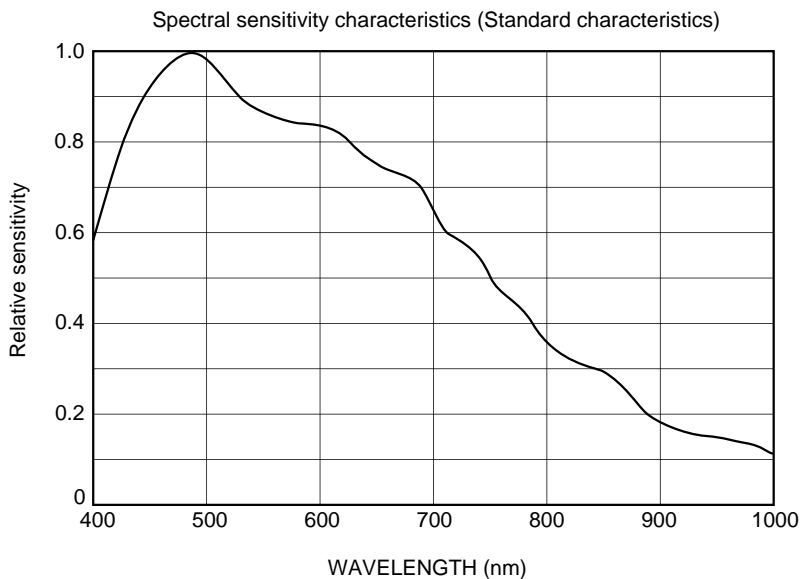
## Clock Pulse Recommended Timing

	Symbol	Min.	Typ.	Max.	Unit
$\phi$ ROG, $\phi$ 1 pulse timing	t1	50	100	—	ns
$\phi$ ROG pulse high level period	t2	600	1000	—	ns
$\phi$ ROG, $\phi$ 1 pulse timing	t3	400	1000	—	ns
$\phi$ ROG pulse rise time	t4	0	5	10	ns
$\phi$ ROG pulse fall time	t5	0	5	10	ns
$\phi$ 1 pulse rise time / $\phi$ 2 pulse fall time	t6	0	20	60	ns
$\phi$ 1 pulse fall time / $\phi$ 2 pulse rise time	t7	0	20	60	ns
$\phi$ RS pulse high level period	t8	20	250*	—	ns
$\phi$ RS, $\phi$ LH pulse timing	t9	0	250*	—	ns
$\phi$ RS pulse rise time	t10	0	10	30	ns
$\phi$ RS pulse fall time	t11	0	10	30	ns
Signal output delay time	t12	—	8	—	ns
	t13	—	8	—	ns
$\phi$ 1, $\phi$ LH pulse low level period/ $\phi$ 2 pulse high level period	t14, t16	25	500*	—	ns
$\phi$ 1, $\phi$ LH pulse high level period/ $\phi$ 2 pulse low level period	t15, t17	25	500*	—	ns

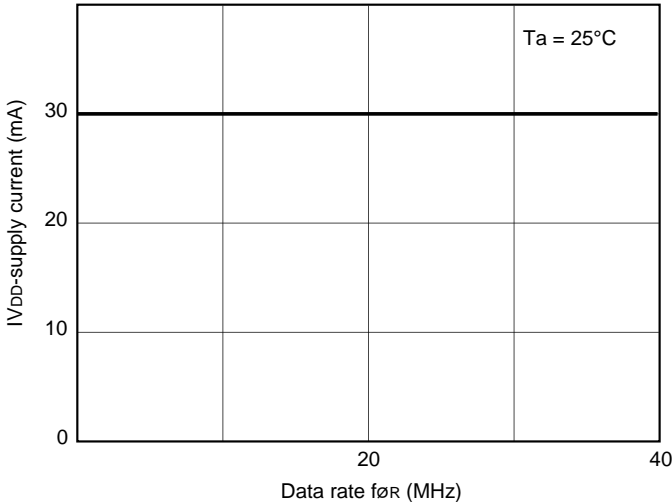
(\*) These timing is the recommended condition under  $f\phi$ 1=1 MHz.



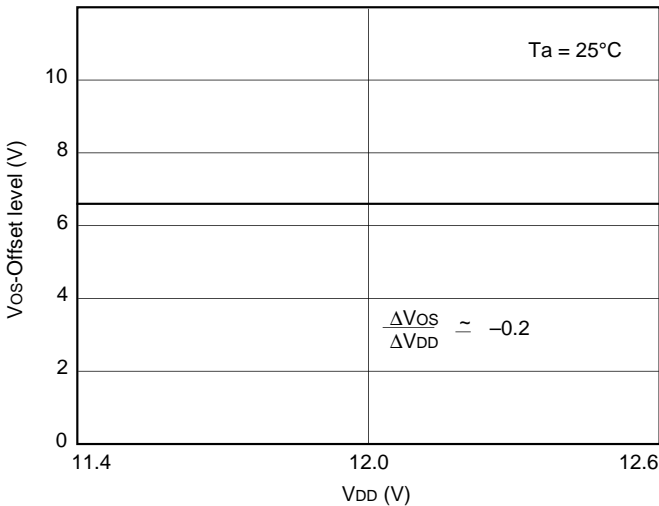
Example of Representative Characteristics ( $V_{DD} = 12\text{ V}$ ,  $T_a = 25\text{ }^\circ\text{C}$ )



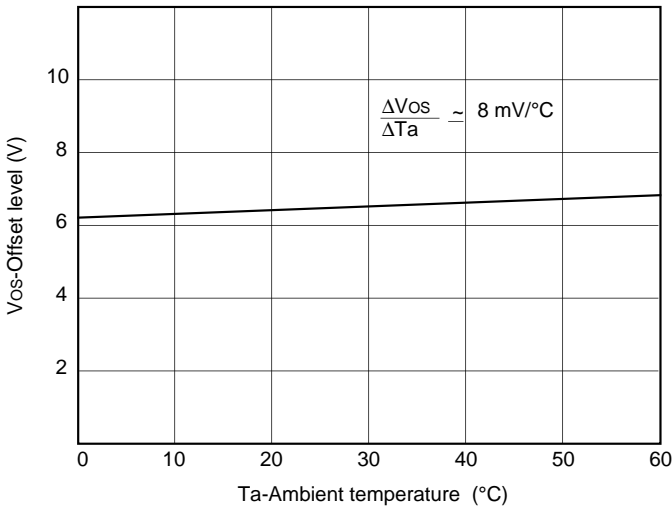
Operational frequency response of supply supply current  
(Standard characteristics)



Offset level vs. V<sub>DD</sub> characteristics  
(Standard characteristics)



Offset level vs. Temperature characteristics  
(Standard characteristics)



## Notes of Handling

### 1) Static charge prevention

CCD image sensors are easily damaged by static discharge. Before handling be sure to take the following protective measures.

- Either handle bare handed or use non chargeable gloves, clothes or material. Also use conductive shoes.
- When handling directly use an earth band.
- Install a conductive mat on the floor or working table to prevent the generation of static electricity.
- Ionized air is recommended for discharge when handling CCD image sensor.
- For the shipment of mounted substrates, use boxes treated for prevention of static charges.

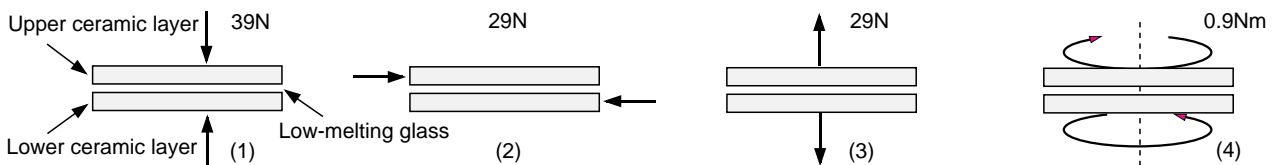
### 2) Notes on Handling CCD Cer-DIP Packages

The following points should be observed when handling and installing cer-DIP packages.

a) Remain within the following limits when applying static load to the ceramic portion of the package:

- Compressive strength: 39 N/surface (Do not apply load more than 0.7 mm inside the outer perimeter of the glass portion.)
- Shearing strength: 29 N/surface
- Tensile strength: 29 N/surface
- Torsional strength: 0.9 Nm

b) In addition, if a load is applied to the entire surface by a hard component, bending stress may be generated and the package may fracture, etc., depending on the flatness of the ceramic portion. Therefore, for installation, either use an elastic load, such as a spring plate, or an adhesive.



c) Be aware that any of the following can cause the glass to crack: because the upper and lower ceramic layers are shielded by low-melting glass,

- Applying repetitive bending stress to the external leads.
- Applying heat to the external leads for an extended period of time with soldering iron
- Rapid cooling or heating
- Rapid cooling or impact to a limited portion of the low-melting glass with a small-tipped tool such as tweezers.
- Prying the upper or lower ceramic layers away at a support point of the low-melting glass.

Note that the preceding notes should also be observed when removing a component from a board after it has already been soldered.

### 3) Soldering

- Make sure the package temperature does not exceed 80 °C.
- Solder dipping in a mounting furnace causes damage to the glass and other defects. Use a grounded 30 W soldering iron and solder each pin in less than 2 seconds. For repairs and remount, cool sufficiently.
- To dismount an imaging device, do not use a solder suction equipment. When using an electric desoldering tool, ground the controller. For the control system, use a zero cross type.

- 4) Dust and dirt protection
  - a) Operate in clean environments.
  - b) Do not either touch glass plates by hand or have any object come in contact with glass surfaces. Should dirt stick to a glass surface, blow it off with an air blower. (For dirt stuck through static electricity ionized air is recommended.)
  - c) Clean with a cotton bud and ethyl alcohol if the glass surface is grease stained. Be careful not to scratch the glass.
  - d) Keep in a case to protect from dust and dirt. To prevent dew condensation, preheat or precool when moving to a room with great temperature differences.
- 5) Exposure to high temperatures or humidity will affect the characteristics. Accordingly avoid storage or usage in such conditions.
- 6) CCD image sensors are precise optical equipment that should not be subject to mechanical shocks.

